

# Leadless High Speed Switching Diode

## RLS-73

### ●Application

High speed switching

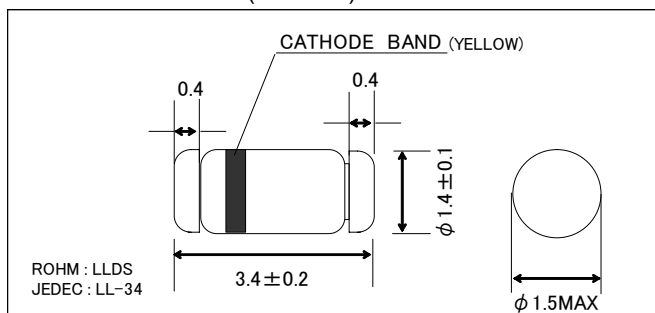
### ●Features

- 1) Ultra small. (LLDS)
- 2) For surface mounting
- 3) High speed ( $t_{rr}=2\text{ns Typ.}$ ) & high reliability.

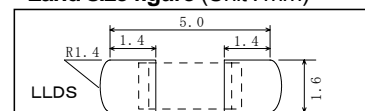
### ●Construction

Silicon epitaxial planar

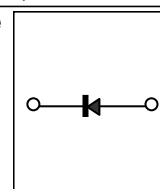
### ●External dimensions (Unit : mm)



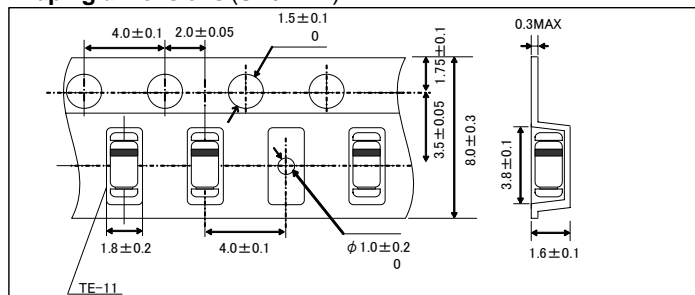
### ●Land size figure (Unit : mm)



### ●Structure



### ●Taping dimensions (Unit : mm)



### ●Absolute maximum ratings (Ta=25°C)

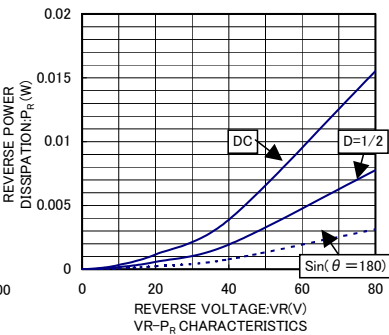
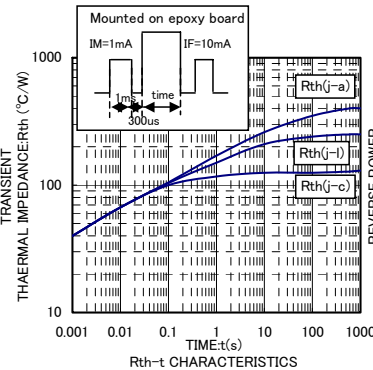
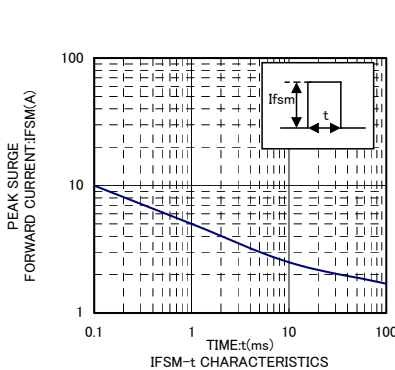
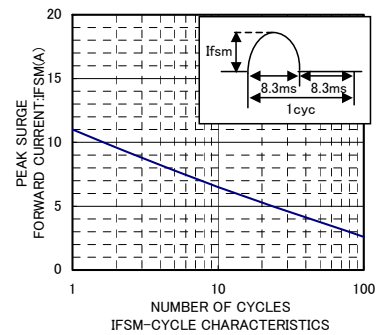
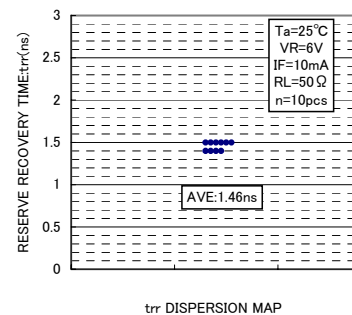
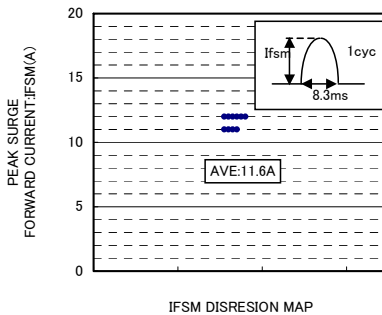
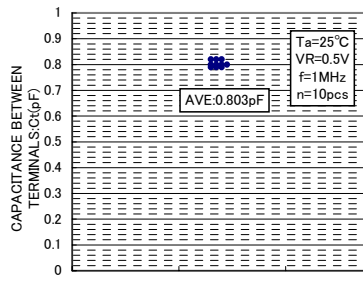
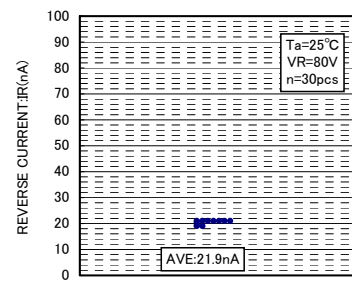
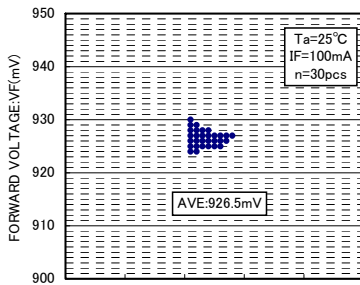
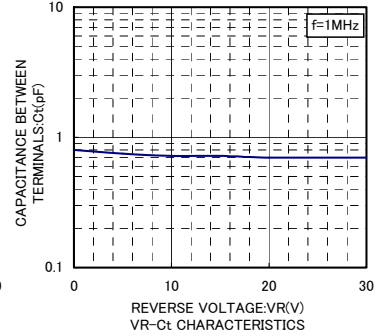
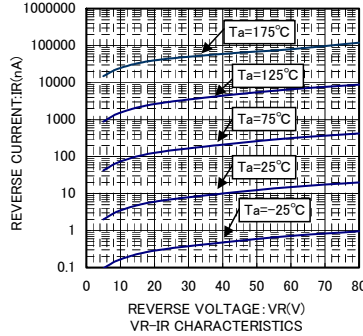
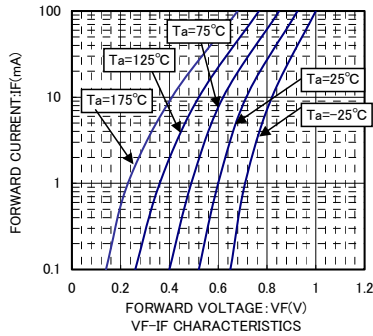
Parameter	Symbol	Limits	Unit
Reverse voltage (repetitive peak)	$V_{RM}$	90	V
Reverse voltage (DC)	$V_R$	80	V
Peak reverse current	$I_{FM}$	400	mA
Average rectified forward current	$I_o$	130	mA
Surge current (1s)	$I_{surge}$	600	mA
Power dissipation	P	300	mW
Junction temperature	$T_j$	175	°C
Storage temperature	$T_{stg}$	-65 to +175	°C

### ●Electrical characteristics (Ta=25°C)

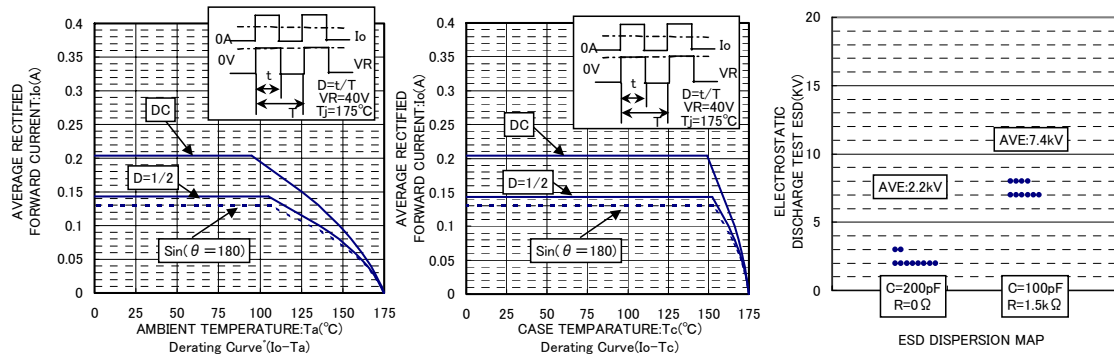
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	$V_F$	-	-	1.2	V	$I_F=100\text{mA}$
Reverse current	$I_R$	-	-	0.5	$\mu\text{A}$	$V_R=80\text{V}$
Capacitance between terminals	$C_t$	-	-	2.0	pF	$V_R=0.5\text{V}$ , $f=1\text{MHz}$
Reverse recovery time	$T_{rr}$	-	-	4.0	ns	$V_R=6.0\text{V}$ , $I_F=10\text{mA}$ , $R_L=50\Omega$

# Diodes

## ●Electrical characteristic curves (Ta=25°C)



# Diodes



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